

# FFP12UP20DN

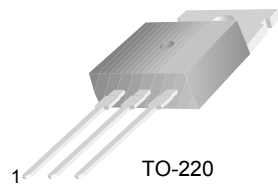
## Ultrafast Recovery Power Rectifier

### Features

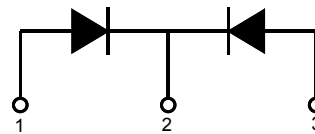
- Ultrafast with Soft Recovery : < 35ns (@ $I_F = 6A$ )
- High Reverse Voltage :  $V_{RRM} = 200V$
- Enhanced Avalanche Energy Rated
- Planar Construction

### Applications

- Output Rectifiers
- Switching Mode Power Supply
- Free-wheeling Diode
- Power Switching Circuits



1.Anode 2.Cathode 3.Anode



1. Anode 2. Cathode 3. Anode

### Absolute Maximum Ratings (per diode) $T_C = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{RRM}$	Peak Repetitive Reverse Voltage	200	V
$V_{RWM}$	Working Peak Reverse Voltage	200	V
$V_R$	DC Blocking Voltage	200	V
$I_{F(AV)}$	Average Rectified Forward Current @ $T_C = 125^\circ C$	6	A
$I_{FSM}$	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	60	A
$T_J, T_{STG}$	Operating Junction and Storage Temperature	- 65 to +150	$^\circ C$

### Thermal Characteristics

Symbol	Parameter	Max	Units
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	3.5	$^\circ C/W$

### Package Marking and Ordering Information

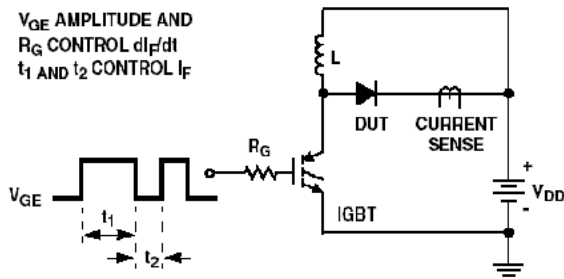
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
F12UP20DN	FFP12UP20DNTU	TO-220	-	-	50

### Electrical Characteristics (per diode) $T_C = 25^\circ\text{C}$ unless otherwise noted

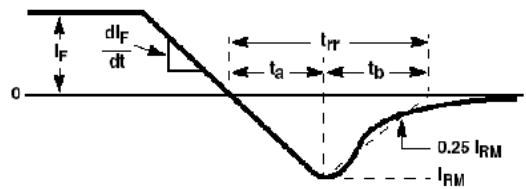
Symbol	Parameter	Min.	Typ.	Max.	Units
$V_{FM}^*$	$I_F = 6\text{A}$	-	-	1.15	V
	$I_F = 6\text{A}$	-	-	1.0	V
$I_{RM}^*$	$V_R = 200\text{V}$	-	-	100	$\mu\text{A}$
	$V_R = 200\text{V}$	-	-	500	$\mu\text{A}$
$t_{rr}$	$I_F = 1\text{A}, di/dt = 100\text{A}/\mu\text{s}, V_{CC} = 30\text{V}$	-	-	30	ns
	$I_F = 6\text{A}, di/dt = 200\text{A}/\mu\text{s}, V_{CC} = 130\text{V}$	-	-	35	ns
$t_a$ $t_b$ $Q_{rr}$	$I_F = 6\text{A}, di/dt = 200\text{A}/\mu\text{s}, V_{CC} = 130\text{V}$	$T_C = 25^\circ\text{C}$	-	12	ns
		$T_C = 25^\circ\text{C}$	-	12	ns
		$T_C = 25^\circ\text{C}$	-	24	nC
$W_{AVL}$	Avalanche Energy ( $L = 20\text{mH}$ )	10	-	-	mJ

\* Pulse Test: Pulse Width=300 $\mu\text{s}$ , Duty Cycle=2%

### Test Circuit and Waveforms

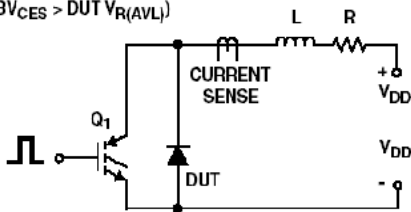


$t_{rr}$  TEST CIRCUIT

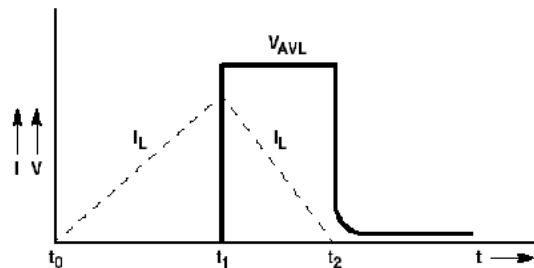


$t_{rr}$  WAVEFORMS AND DEFINITIONS

- $I_{MAX} = 1\text{A}$
- $L = 20\text{mH}$
- $R < 0.1\Omega$
- $E_{AVL} = 1/2LI^2 [V_{R(AVL)}/(V_{R(AVL)} - V_{DD})]$
- $Q_1 = \text{IGBT (}BV_{CES} > \text{DUT } V_{R(AVL)}\text{)}$



AVALANCHE ENERGY TEST CIRCUIT



AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

## Typical Performance Characteristics

Figure 1. Typical Forward Voltage Drop

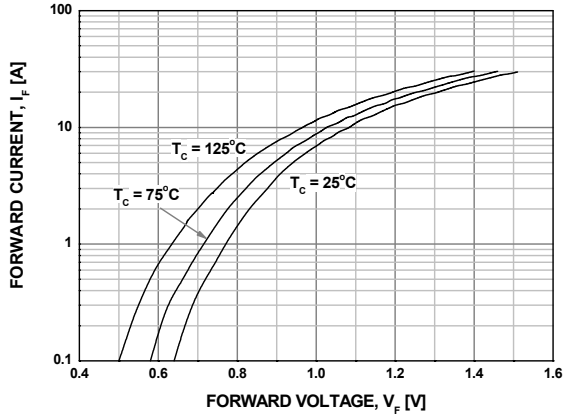


Figure 2. Typical Reverse Current

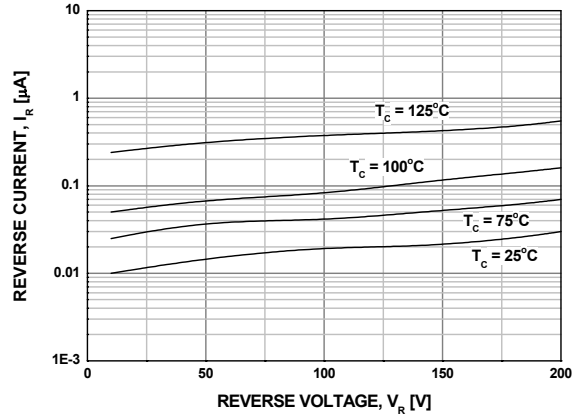


Figure 3. Typical Junction Capacitance

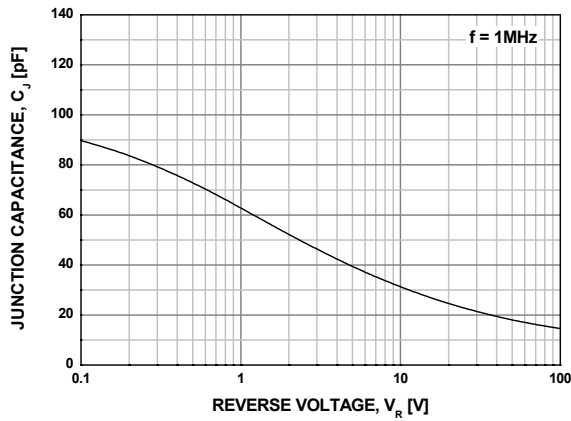


Figure 4. Typical Reverse Recovery Time

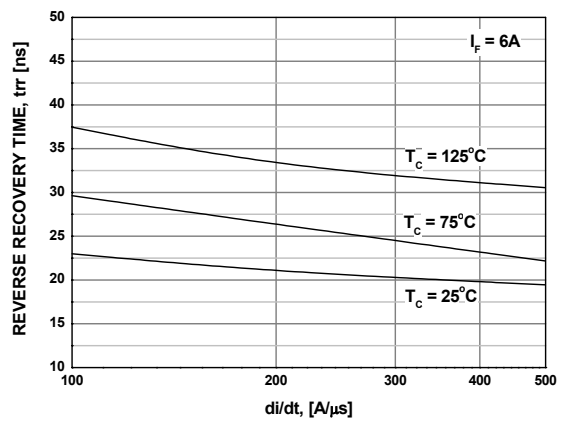


Figure 5. Typical Reverse Recovery Current

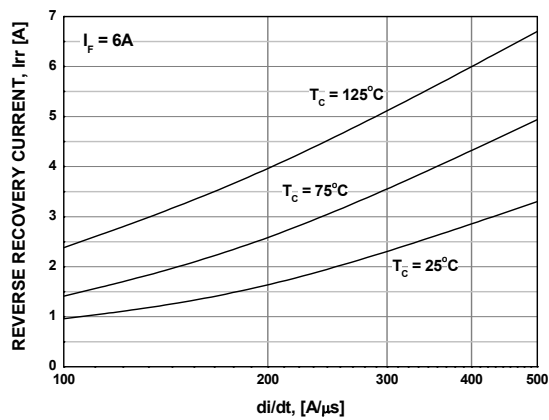
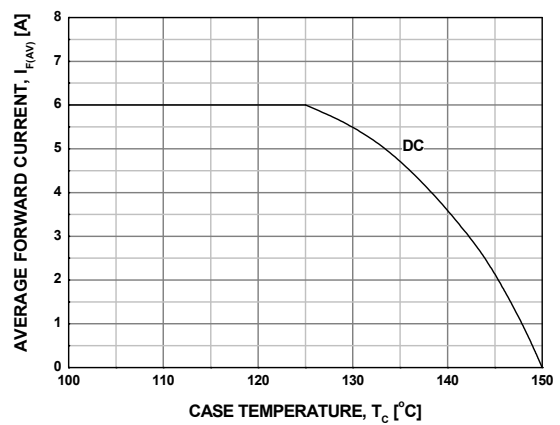
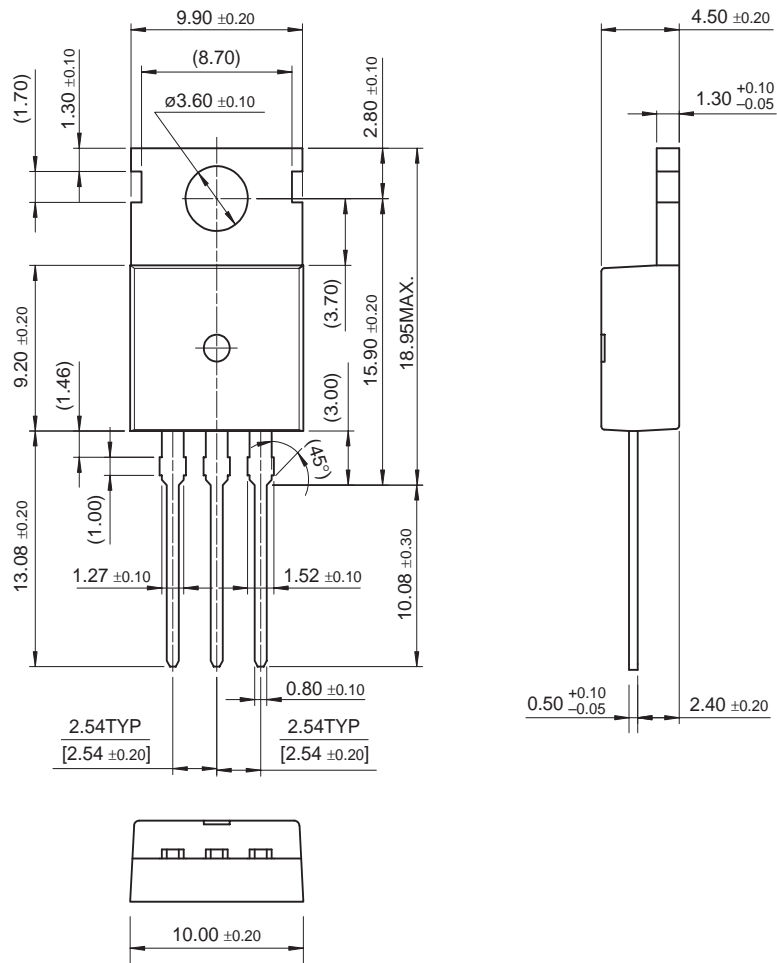


Figure 6. Forward Current Deration Curve



Package Demensions

TO-220



Dimensions in Millimeters

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		PACMAN™	SPM™	
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Programmable Active Droop™		PowerEdge™	SuperSOT™-3	

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